NSN 5961-01-356-8149

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-356-8149 **Inclosure Material:** Metal **Overall Length:** 1.430 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1.15 forward voltage, peak and 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 85.00 amperes collector current, dc absolute and 1500.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Special Features:** Nuclear hardness critical item **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: